RP602x Series

1.5 A PWM/VFM Buck-Boost DC/DC Converter with Synchronous Rectifier

No. EA-353-190507

OVERVIEW

The RP602x is a 6.5 V (Max. rating) buck-boost DC/DC converter with synchronous rectifier. This device is ideally suited for industrial or OA equipment that require constant voltage even when low-input voltage (Min. 2.3 V). Since operating with switching frequency of 2.6 MHz, this device can realize a high-speed response with a small coil and maintain a high-efficiency at low input voltage.

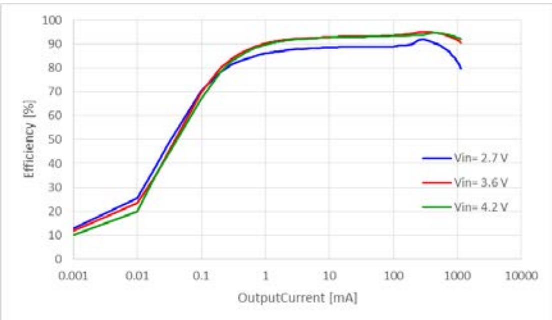
KEY BENEFITS

- **Realize a high-efficiency at low input voltage.**
- **Provide output voltage of 2.7 to 4.2 V corresponding to input voltage of 2.3 to 5.5 V.**

KEYSPECIFICATIONS

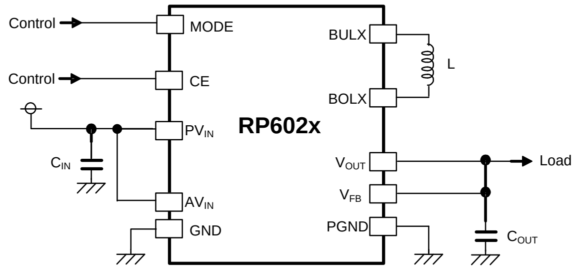
- Input Voltage Range:2.3 V to 5.5 V
- Output Voltage Range:2.7 V to 4.2 V (0.1V step)
- Output Voltage Accuracy :±1.5%
- Line Regulation: Typ. 0.5%, PWM mode
- Load Regulation: Typ. 0.1%, (I_{OUT} = 0 to 500 mA, PWM mode)
- Maximum Output Current: Typ. 1.5 A, (PVIN = 3 V, VOUT = 3.3 V)
- Maximum Burst Current: Typ. 2.7 A, (PVIN=3 V, VOUT=3.3 V, Duty=10%, t=2.0 ms)
- Overcurrent Limit Protection: Typ. 4.2 A
- Oscillator Frequency: Typ. 2.6 MHz
- Built-in Driver ON Resistance: Typ. Pch. 80 mΩ, Nch. 80 mΩ
- Operating Quiescent Current: Typ. 27.5 µA, (VFM mode, Non-switching)
- UVLO Detector Threshold: Typ. 2.0 V
- Soft-start Time: Typ. 1.0 ms
- Thermal Shutdown Temperature:Typ.150°C
- Protection Feature: Overvoltage, Overcurrent

TYPICAL CHARACTERISTICS



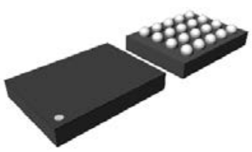
Efficiency Characterisitcs (RP602Z330x, MODE = H)

TYPICAL APPLICATION



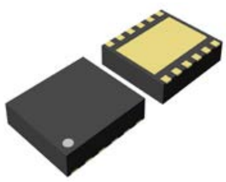
PACKAGE

RP602Z



WLCSP-20-P1
2.305 mm x 1.700 mm

RP602K



DFN(PLP)2730-12
2.7mm × 3.0mm

OPTIONAL FUNCTION

The following functions are user-selectable options.

Code	Auto-discharge Function	Latch Protection	Reset Protection
A/E	Yes	Yes	No
B/F	No	Yes	No
C/G	Yes	No	Yes
D/H	No	No	Yes

APPLICATIONS

- Power source for portable equipment such as laptops, PDAs, DSCs, cellular phones, and smartphones
- Power source for Li-ion battery-used equipment

SELECTION GUIDE

Selection Guide

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
RP602Zxxx$-E2-F	WLCSP-20-P1	5,000 pcs	Yes	Yes
RP602Kxxx#-TR	DFN(PLP)2730-12	5,000 pcs	Yes	Yes

xxx: Specify the set output voltage (V_{SET}) within the range of 2.7 V to 4.2 V in 0.1 V [1] steps.

$: Specify the combination of the auto-discharge option and the protection function option.

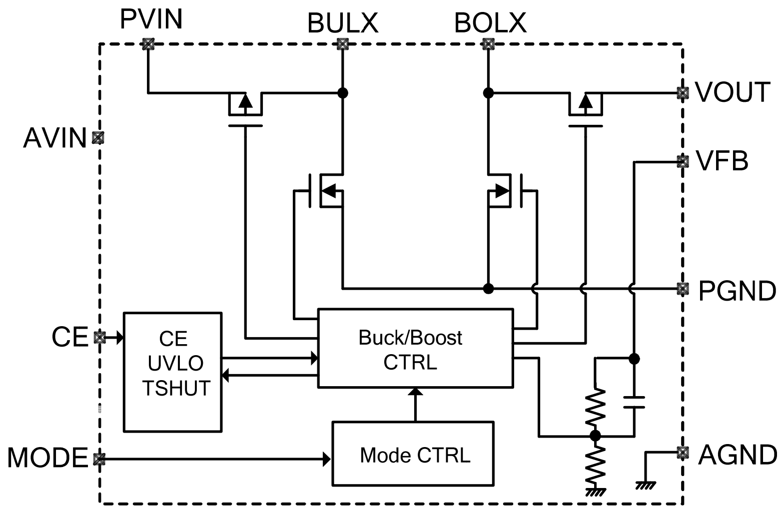
Symbol	Auto-discharge Function	Latch-type Protection	Reset-type Protection	Short-circuit Protection
A	Yes	Yes	No	Yes
B	No	Yes	No	Yes
C	Yes	No	Yes	Yes
D	No	No	Yes	Yes

#: Specify the combination of the auto-discharge option and the protection function option.

Symbol	Auto-discharge Function	Latch-type Protection	Reset-type Protection	Short-circuit Protection
E	Yes	Yes	No	Yes
F	No	Yes	No	Yes
G	Yes	No	Yes	Yes
H	No	No	Yes	Yes

[1] 0.05 V step is also available as a custom code.

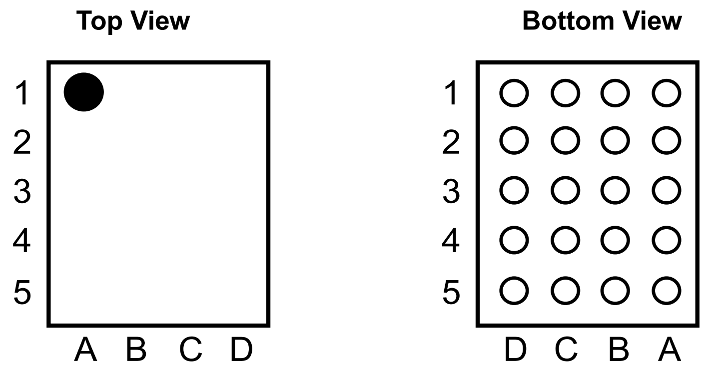
BLOCK DIAGRAM



RP602x Block Diagram

PIN DESCRIPTION

RP602Z Pin Description



WLCSP-20-P1 Pin Configuration

Pin No.	Symbol	Pin Description
A5, B5, C5	VOUT (1)	Output Voltage Pin
A4, B4, C4	BOLX (1)	Boost Switching Output Pin
A3, B3, C3	PGND (2)	Power GND Pin
A2, B2, C2	BULX (1)	Buck Switching Output Pin
A1, B1, C1	PVIN (1)	Power Input Voltage Pin
D1	AVIN (1)	Analog Power Input Voltage Pin
D2	CE	Chip Enable Pin, Active-high
D3	MODE	Mode Control Pin, Forced PWM Control: L, PWM/VFM Auto Switching Control: H
D4	AGND (2)	Analog GND Pin
D5	VFB	Output Voltage Feedback Pin

Pin Truth Table

CE Pin	MODE Pin (3)	Operation
L	-	OFF
H	H	PWM/ VFM Auto Switching Control Mode
	L	Forced PWM Control Mode

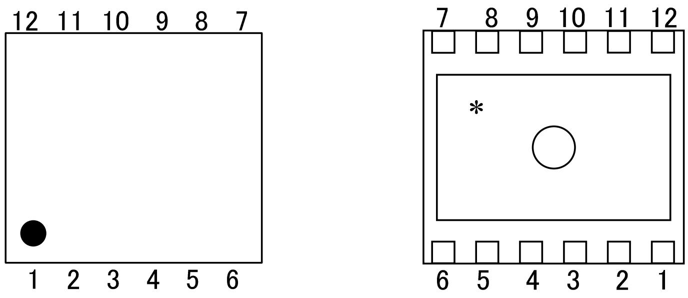
(1) The pin numbers sharing the same pin symbol must be connected together: A4, B4, and C4 of the BOLX pin, A2, B2, and C2 of the BULX pin, A5, B5, and C5 of the VOUT pin. D1 of the AVIN pin and A1, B1, and C1 of the PVIN pin must be connected together.

(2) D4 of the AGND pin and A3, B3, and C3 of the PGND pin must be connected to the ground.

(3) The logic to the MODE pin should not be changed while CE = “H”.

RP602K Pin Description

Top View　　　　Bottom View



DFN(PLP)2730-12 Pin Configuration

Pin No.	Symbol	Pin Description
1	AVIN (1)	Analog Power Input Voltage Pin
2	CE	Chip Enable Pin, Active-high
3	MODE	Mode Control Pin, Forced PWM Control: L, PWM/VFM Auto Switching Control: H
4	NC	No Connection
5	AGND (2)	Analog GND Pin
6	VFB	Output Voltage Feedback Pin
7	VOUT	Output Voltage Pin
8	BOLX	Boost Switching Output Pin
9,10	PGND (2)	Power GND Pin
11	BULX	Buck Switching Output Pin
12	PVIN (1)	Power Input Voltage Pin

∗ The tab on the bottom of the package must be connected to the ground plane on the board to enhance thermal performance.

Pin Truth Table

CE Pin	MODE Pin (3)	Operation
L	-	OFF
H	H	PWM/ VFM Auto Switching Control Mode
	L	Forced PWM Control Mode

(1) The AVIN pin and the PVIN pin must be connected together.
(2) The AGND pin and the PGND pin must be connected to the ground.
(3) The logic to the MODE pin should not be changed while CE = “H”.

RICOH

ABSOLUTE MAXIMUM RATINGS

Absolute Maximum Ratings (AGND = PGND = 0 V)

Symbol	Item		Rating	Unit
V_{IN}	AVIN/ PVIN Pin Voltage		−0.3 to 6.5	V
V_{BULX}	BULX Pin Voltage		−0.3 to V_{IN} + 0.3	V
V_{BOLX}	BOLX Pin Voltage		−0.3 to V_{OUT} + 0.3	V
V_{CE}	CE Pin Voltage		−0.3 to 6.5	V
V_{MODE}	MODE Pin Voltage		−0.3 to 6.5	V
V_{OUT}	VOUT Pin Voltage		−0.3 to 6.5	V
V_{FB}	VFB Pin Voltage		−0.3 to 6.5	V
I_{LX}	BULX/ BOLX Pin Output Current		4.2	A
P_D	Power Dissipation [1]	WLCSP-20-P1 (JEDEC STD.51-9)	1400	mW
		DFN(PLP)2730-12 (JEDEC STD.51-7)	3100	
Tj	Junction Temperature Range		−40 to 125	°C
Tstg	Storage Temperature Range		−55 to 125	°C

ABSOLUTE MAXIMUM RATINGS
Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause permanent damage and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings are not assured.

RECOMMENDED OPERATING CONDITIONS

Symbol	Item	Rating	Unit
V_{IN}	Input Voltage	2.3 to 5.5	V
Ta	Operating Temperature Range	−40 to 85	°C

RECOMMENDED OPERATING CONDITIONS
All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if they are used over such ratings by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

[1] Refer to *POWER DISSIPATION* for detailed information.

ELECTRICAL CHARACTERISTICS

Open-loop Measurement GND = 0 V, unless otherwise noted.

RP602Z Electrical Characteristics (Ta = 25°C)

Symbol	Item	Conditions		Min.	Typ.	Max.	Unit
I_{DD}	Power Current	V_{IN} = 5.5 V, V_{OUT} = 4.2 V	V_{MODE} = 5.5V		27.5	60	μA
			V_{MODE} = 0 V		1000	1400	
$I_{STANDBY}$	Standby Current	V_{IN} = 5.5 V, V_{CE} = 0 V			0.1	5.0	μA
V_{OUT}	Output Voltage	V_{IN} = 3.6 V		x0.985		x1.015	V
$\Delta V_{OUT}/\Delta Ta$	Output Voltage Temperature Coefficient	−40°C ≤ Ta ≤ 85°C			±50		ppm/°C
V_{OVP}	OVP Detection Voltage	V_{IN} = 3.6 V , Rising		4.5	5.0	5.5	V
	OVP Release Voltage	V_{IN} = 3.6 V , Falling		4.3	4.8	5.3	V
f_{OSC}	Switching Frequency	V_{IN} = 3.6 V		2.4	2.6	2.9	MHz
I_{LIMHS}	BULX Current Limit (1)	V_{IN} = 3.6 V		3.7	4.2		A
R_{ON}	High & Low Switch On-resistance	V_{IN} = 3.6 V			80		mΩ
R_{DIS}	On-resistance of Discharge Tr. (RP602ZxxxA/C)	V_{IN} = 3.6 V, V_{CE} = 0 V			80		Ω
I_{FBH}	V_{FB} Input Current, High	V_{IN} = 5.5 V, V_{CE} = 0 V V_{FB} = 5.5V				1	μA
I_{FBL}	V_{FB} Input Current, Low	V_{IN} = 5.5 V, V_{CE} = 0 V V_{FB} = 0V				1	μA
V_H	CE / MODE Pins Input Voltage, High	V_{IN} = 5.5 V		1.0			V
V_L	CE / MODE Pins Input Voltage, Low	V_{IN} = 2.3 V				0.4	V
I_H	CE / MODE Pins Input Current, High	V_{IN} = V_{CE} = 5.5 V		−1	0	1	μA
I_L	CE / MODE Pins Input Current, Low	V_{IN} = 5.5 V, V_{CE} = 0 V		−1	0	1	μA
V_{UVLO1}	UVLO Detection Voltage	V_{IN} = Falling		1.83	2.00		V
V_{UVLO2}	UVLO Release Voltage	V_{IN} = Rising			2.05	2.25	V
T_{TSD}	Thermal Shutdown Threshold Temperature	Tj, Rising			150		°C
T_{TSR}		Tj, Falling			110		°C
t_{START}	Soft-start Time	V_{IN} = 3.6 V			1		ms
t_{PROT}	Protection Delay Time (RP602ZxxxA/B/C/D)	V_{IN} = 3.6 V			1.6		ms
t_{RST}	Reset Protection Delay Time (RP602ZxxxC/D)	V_{IN} = 3.6 V			12		ms

All test items listed under *ELECTRICAL CHARACTERISTICS* are done under the pulse load condition (Tj ≈ Ta = 25°C).

(1) BULX Current Limit vary according to the switching duty ratio.

Open-loop Measurement GND = 0 V, unless otherwise noted.

RP602K Electrical Characteristics (Ta = 25°C)

Symbol	Item	Conditions		Min.	Typ.	Max.	Unit
I_{DD}	Power Current	V_{IN} = 5.5 V, V_{OUT} = 4.2 V,	V_{MODE} = 5.5 V		27.5	60	µA
			V_{MODE} = 0 V		1000	1400	
$I_{STANDBY}$	Standby Current	V_{IN} = 5.5 V, V_{CE} = 0 V			0.1	5.0	µA
V_{OUT}	Output Voltage	V_{IN} = 3.6 V		x0.985		x1.015	V
$\Delta V_{OUT}/\Delta Ta$	Output Voltage Temperature Coefficient	−40°C ≤ Ta ≤ 85°C			±50		ppm/°C
V_{OVP}	OVP Detection Voltage	V_{IN} = 3.6 V , Rising		4.5	5.0	5.5	V
	OVP release Voltage	V_{IN} = 3.6 V , Falling		4.3	4.8	5.3	V
f_{OSC}	Switching Frequency	V_{IN} = 3.6 V		2.4	2.6	2.9	MHz
I_{LIMHS}	BULX Current Limit [1]	V_{IN} = 3.6 V		3.7	4.2		A
R_{ON}	High & Low Switch On-resistance	V_{IN} = 3.6 V			120		mΩ
R_{DIS}	On-resistance of Discharge Tr. (RP602KxxxE/G)	V_{IN} = 3.6 V, V_{CE} = 0 V			80		Ω
I_{FBH}	V_{FB} Input Current, High	V_{IN} = 5.5 V, V_{CE} = 0 V V_{FB} = 5.5V				1	µA
I_{FBL}	V_{FB} Input Current, Low	V_{IN} = 5.5 V, V_{CE} = 0 V V_{FB} = 0V				1	µA
V_H	CE / MODE Pins Input Voltage, High	V_{IN} = 5.5 V		1.0			V
V_L	CE / MODE Pins Input Voltage, Low	V_{IN} = 2.3 V				0.4	V
I_H	CE / MODE Pins Input Current, High	V_{IN} = V_{CE} = 5.5 V		−1	0	1	µA
I_L	CE / MODE Pins Input Current, Low	V_{IN} = 5.5 V, V_{CE} = 0 V		−1	0	1	µA
V_{UVLO1}	UVLO Detection Voltage	V_{IN} = Falling		1.83	2.00		V
V_{UVLO2}	UVLO Release Voltage	V_{IN} = Rising			2.05	2.25	V
T_{TSD}	Thermal Shutdown Threshold Temperature	Tj, Rising			150		°C
T_{TSR}		Tj, Falling			110		°C
t_{START}	Soft-start Time	V_{IN} = 3.6 V			1		ms
t_{PROT}	Protection Delay Time (RP602KxxxE/F/G/H)	V_{IN} = 3.6 V			1.6		ms
t_{RST}	Reset Protection Delay Time (RP602KxxxG/H)	V_{IN} = 3.6 V			12		ms

All test items listed under *ELECTRICAL CHARACTERISTICS* are done under the pulse load condition (Tj ≈ Ta = 25°C).

[1] BULX Current Limit vary according to the switching duty ratio.

Product-specific Electrical Characteristics (Ta = 25°C)

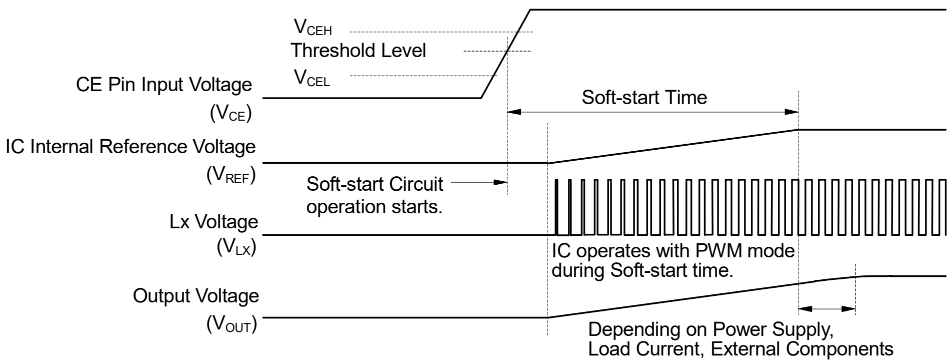
Product Name	V_{OUT} (V)		
	Min.	Typ.	Max.
RP602x270x	2.660	2.700	2.740
RP602x280x	2.758	2.800	2.842
RP602x290x	2.857	2.900	2.943
RP602x300x	2.955	3.000	3.045
RP602x310x	3.054	3.100	3.146
RP602x320x	3.152	3.200	3.248
RP602x330x	3.251	3.300	3.349
RP602x340x	3.349	3.400	3.451
RP602x350x	3.448	3.500	3.552
RP602x360x	3.546	3.600	3.654
RP602x370x	3.645	3.700	3.755
RP602x380x	3.743	3.800	3.857
RP602x390x	3.842	3.900	3.958
RP602x400x	3.940	4.000	4.060
RP602x410x	4.039	4.100	4.161
RP602x420x	4.137	4.200	4.263

THEORY OF OPERATION

Soft-start Time

Starting-up with CE Pin

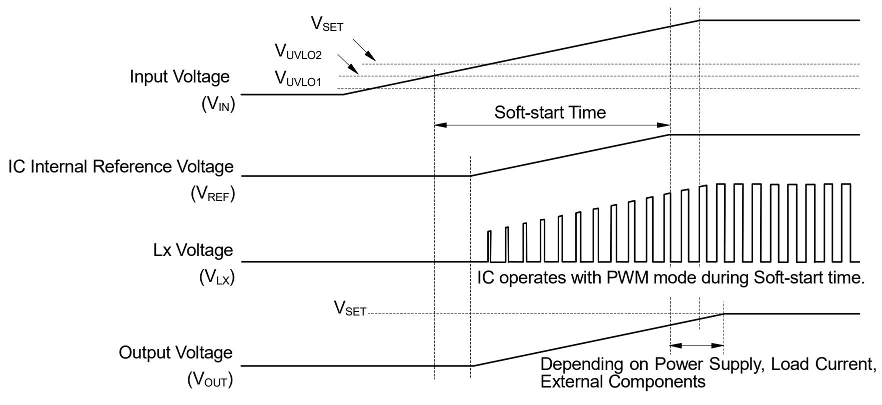
The IC starts to operate when the CE pin voltage (V_{CE}) exceeds the threshold voltage. The threshold voltage is preset between CE "High" input voltage (V_{CEH}) and CE "Low" input voltage (V_{CEL}). After the start-up of the IC, soft-start circuit starts to operate. Then, after a certain period of time, the reference voltage (V_{REF}) in the IC gradually increases up to the specified value. Soft-start time (t_{START}) starts when soft-start circuit is activated, and ends when the reference voltage reaches the specified voltage. Soft start time is not always equal to the turn-on speed of the DC/DC converter. Note that the turn-on speed could be affected by the power supply capacity, the output current, the inductance value and the C_{OUT} value.



Timing Chart: Starting-up with CE Pin

Starting-up with Power Supply

After the power-on, when V_{IN} exceeds the UVLO release voltage (V_{UVLO2}), the IC starts to operate. Then, soft-start circuit starts to operate and after a certain period of time, V_{REF} gradually increases up to the specified value. Soft-start time starts when soft-start circuit is activated, and ends when V_{REF} reaches the specified voltage. Note that the turn-on speed of V_{OUT} could be affected by the power supply capacity, the output current, the inductance value, the C_{OUT} value and the turn-on speed of V_{IN} determined by C_{IN}.



Timing Chart: Starting-up with Power Supply

Undervoltage Lockout (UVLO) Circuit

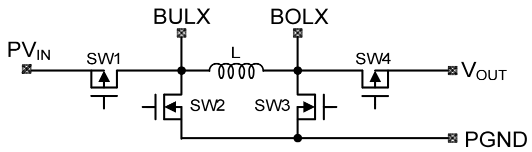
If the V_{IN} becomes lower than the UVLO detection voltage (V_{UVLO1}), the UVLO circuit starts to operate, V_{REF} stops, and P-channel and N-channel built-in switch transistors turn "OFF". As a result, V_{OUT} drops according to the C_{OUT} capacitance value and the load. To restart the operation, V_{IN} needs to be higher than V_{UVLO2}.

Overvoltage Protection (OVP) Circuit

If the V_{OUT} becomes higher than the OVP detection voltage (V_{OVP}), the OVP circuit starts to operate, P-channel and N-channel built-in switch transistors turn "OFF". As a result, V_{OUT} drops according to the C_{OUT} capacitance value and the load.

Overcurrent Protection Circuit

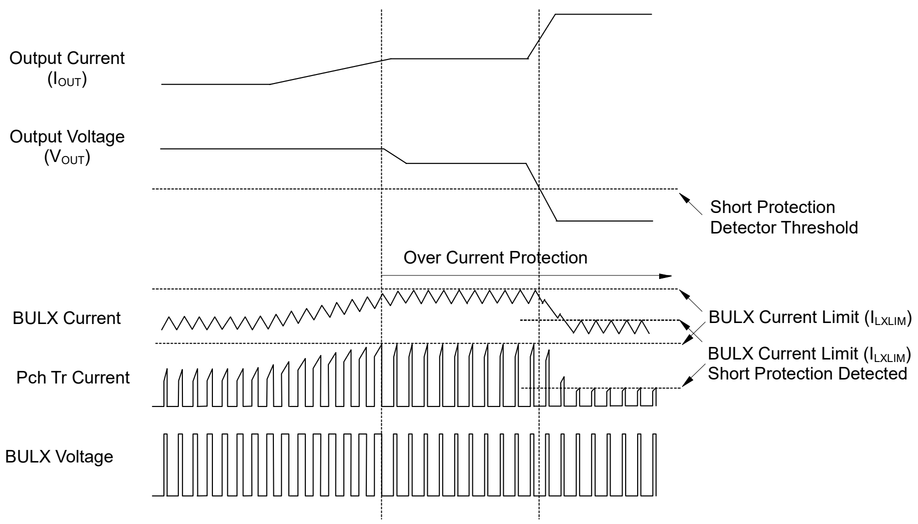
Overcurrent protection circuit supervises the inductor peak current (the peak current flowing through Pch Tr (SW1) in each switching cycle, and if the current exceeds the BULX current limit (I_{LXLIM}), it turns off Pch Tr (SW1). I_{LXLIM} of the RP602x is set to Typ.4200 mA.



Simplified Diagram of Output Switches

Short Protection Circuit

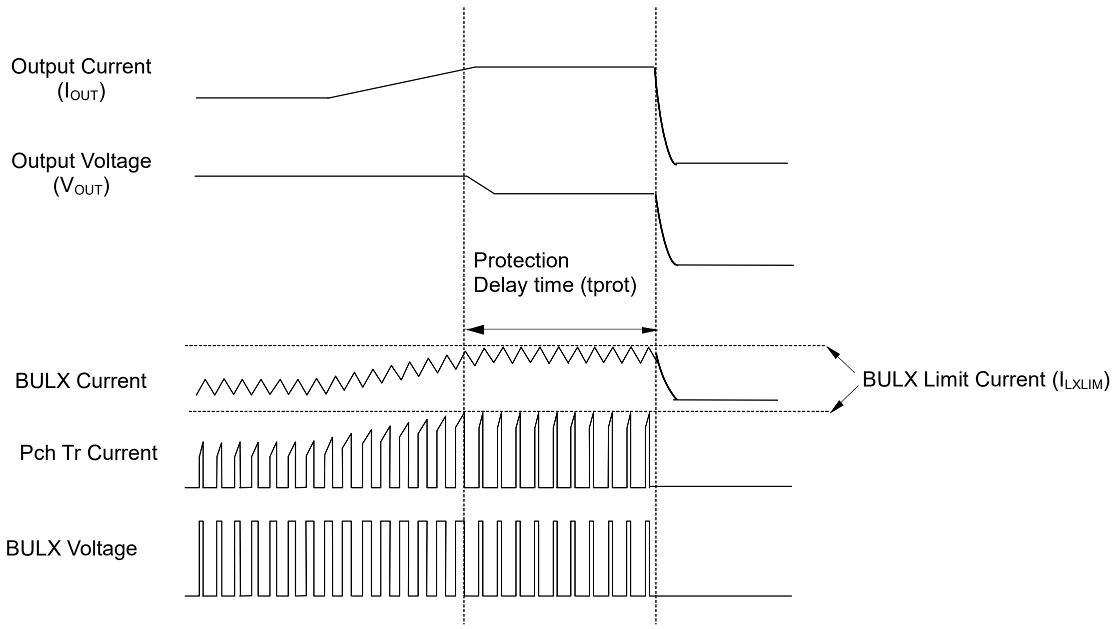
If the V_{OUT} becomes lower than a certain threshold, the BULX current limit is reduced.



Timing Chart: Overcurrent Protection Circuit & Short Protection Circuit

Latch Type Protection Circuit: RP602xxxxA/B/E/F

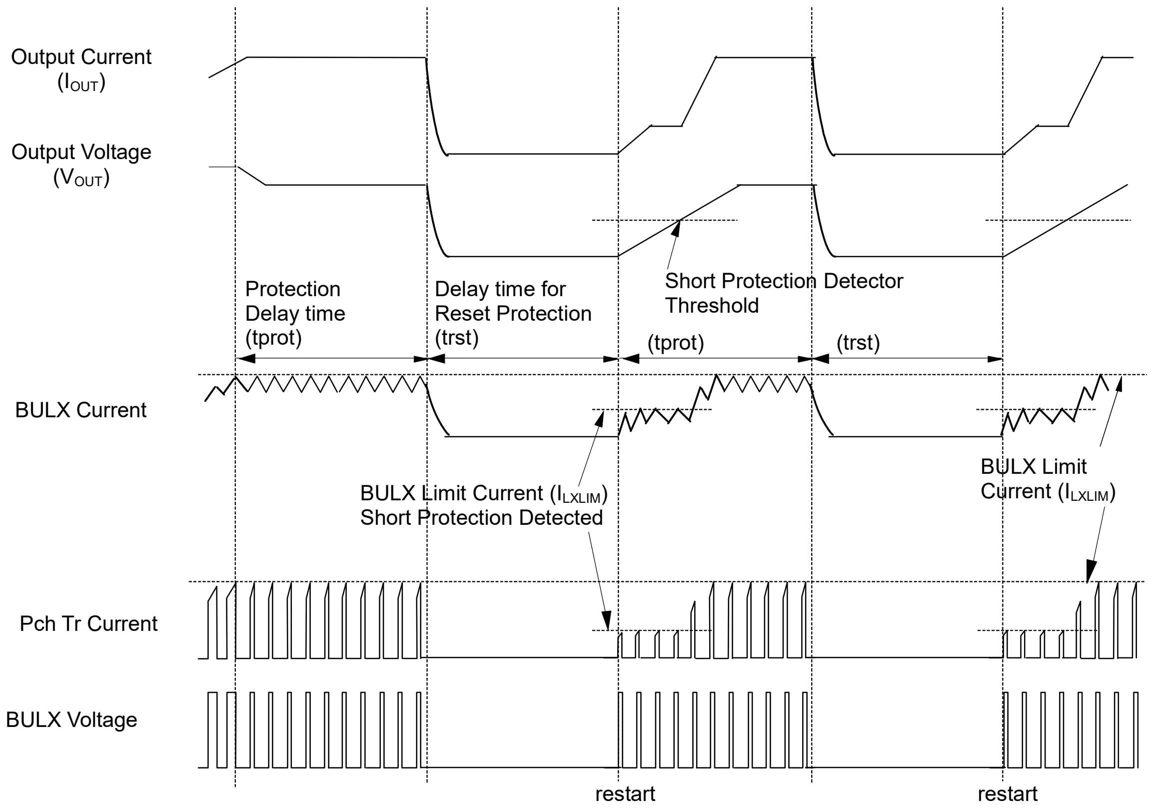
The latch type protection circuit latches the built-in drivers of SW1, SW2, SW3 and SW4 off to stop the operation of the device if the overcurrent state continues more than the protection delay time (t_{PROT}).
To release the latch-type protection, reset the device by switching the CE pin from High to Low or making the input voltage (V_{IN}) lower than the UVLO detection voltage (V_{UVLO1}).



Timing Chart: RP602xxxxA/B/E/F Latch Protection Circuit

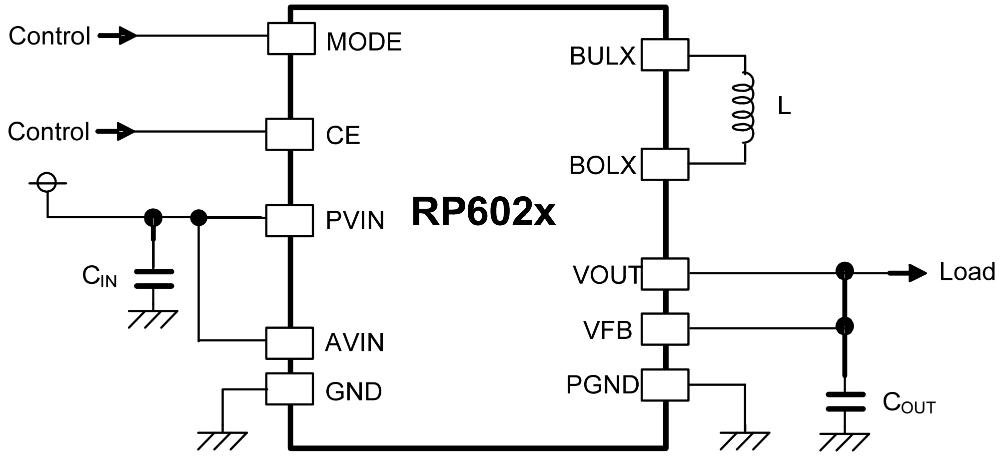
Reset Type Protection Circuit: RP602xxxxC/D/G/H

When the overcurrent state continues more than the protection delay time (t_{PROT}), the reset type protection circuit operates and switching stops. The built-in drivers of SW1, SW2, SW3 and SW4 turn off and restarts after the reset protection delay time (t_{RST}). When the overcurrent state is released, the operation is automatically released and returns to normal operation.



Timing Chart: RP602xxxxC/D/G/H Reset Protection Circuit

APPLICATION INFORMATION



RP602x Typical Application Circuit

Recommended External Components

Symbol	Description
C_{IN} (1)	10 µF, Ceramic, GRM188R60J106ME47, Murata
C_{OUT} (2)	22 µF x 2, Ceramic, GRM188R60J226MEA0, Murata
L	1.0 µH, Inductor, DFE201610P- 1R0M, TOKO 1.0 µH, Inductor, XAL4020- 102ME, Coilcraft

Technical Notes on External Components Selection

- Use ceramic capacitors having a low equivalent series resistance (ESR). C_{OUT} should be paralleled with another C_{OUT}. When selecting the capacitors, consider the bias characteristics and input/ output voltage.
- When the built-in switches are turned off, the inductor may generate a spike-shaped high voltage. Use the high-breakdown voltage capacitor (C_{OUT}) which output voltage is 1.5 times or more than the set output voltage.
- Use an inductor that has a low DC resistance, has an enough tolerable current and is less likely to cause magnetic saturation. If the inductance value is extremely small, the peak current of LX may increase. When the peak current of LX reaches to the LX limit current (I_{LXLIM}), overcurrent protection circuit starts to operate. When selecting the inductor, consider the peak current of LX pin (I_{LXMAX}). Refer to *Calculation Method of Peak Current of LX Pin (I_{LXMAX}) in Continuous Mode* for details.

---

(1) Place C_{IN} as close as possible to the PV_{IN} pin.
(2) Place C_{OUT} as close as possible to the V_{OUT} pin.

Calculation Method of Peak Current of LX Pin (I_{LXMAX}) in Continuous Mode

The peak current of LX pin (I_{LXMAX}) can be calculated as follows, in the case of an ideal buck converter operating in steady conditions, using the components listed in *Recommended External Components* of *APPLICATION INFORMATION*.

Ripple Current P-P value is described as I_{RP}, ON resistance of Pch. Tr. is described as R_{ONP}, ON resistance of Nch. Tr. is described as R_{ONN}, and DC resistor of the inductor is described as R_L.

First, when Pch. Tr. is "ON", the following equation is satisfied.

$V_{IN} = V_{OUT} + (R_{ONP} + R_L) \times I_{OUT} + L \times I_{RP} / t_{ON}$ .... Equation 1

Second, when Pch. Tr. is "OFF" (Nch. Tr. is "ON"), the following equation is satisfied.

$L \times I_{RP} / t_{OFF} = R_{ONN} \times I_{OUT} + V_{OUT} + R_L \times I_{OUT}$ .... Equation 2

Put Equation 2 into Equation 1 to solve ON duty of Pch. Tr. ($D_{ON} = t_{ON} / (t_{OFF} + t_{ON})$):

$D_{ON} = (V_{OUT} + R_{ONN} \times I_{OUT} + R_L \times I_{OUT}) / (V_{IN} + R_{ONN} \times I_{OUT} - R_{ONP} \times I_{OUT})$ .... Equation 3

Ripple Current is described as follows:

$I_{RP} = (V_{IN} - V_{OUT} - R_{ONP} \times I_{OUT} - R_L \times I_{OUT}) \times D_{ON} / fosc / L$ .... Equation 4

Peak current that flows through L, and LX Tr. is described as follows:

$I_{LX}max = I_{OUT} + I_{RP} / 2$ .... Equation 5

RICOH

The peak current of LX pin (I_{LXMAX}) can be calculated as follows, in the case of an ideal boost converter operating in steady conditions, using the components listed in *Recommended External Components* of *APPLICATION INFORMATION*.

Ripple Current P-P value is described as I_{RP}, Average inductor current is described as $I_{LX,}$ ON resistance of Pch. Tr. and ON resistance of Nch. Tr. is described as R_{ONP} and R_{ONN} respectively, and DC resistor of the inductor is described as R_L.

First, when Nch. Tr. is “ON”, the following equation is satisfied.

$L \times I_{RP} / t_{ON} = V_{IN} - (R_L + R_{ONN}) \times I_{LX}$ .... Equation 6

Second, when Nch. Tr. is "OFF" (Pch. Tr. is "ON"), the following equation is satisfied.

$L \times I_{RP} / t_{OFF} = V_{OUT} + (R_L + R_{ONP}) \times I_{LX} - V_{IN}$ .... Equation 7

Put Equation 7 into Equation 6 to solve ON duty of Nch. Tr. ($D_{ON} = t_{ON} / (t_{OFF} + t\ t_{ON})$):

$D_{ON} = (V_{OUT} - V_{IN} + R_L \times I_{LX} + R_{ONP} \times I_{LX}) / (V_{OUT} + R_{ONP} \times I_{LX} - R_{ONN} \times I_{LX})$ .... Equation 8

Ripple Current is described as follows:

$I_{RP} = (V_{IN} - R_L \times I_{LX} - R_{ONN} \times I_{LX}) \times D_{ON} / f_{OSC} / L$ .... Equation 9

Peak current that flows through L (I_{LMAX}), and LX Tr. is described as follows:

$I_{LXMAX} = I_{LX} + I_{RP} / 2$ .... Equation 10

Also, the average peak current (I_{OUT} and D_{ON}) in the boost circuit is described as follows:

$I_{LX} = I_{OUT} / (1 - D_{ON})$ .... Equation 11

RICOH

TECHNICAL NOTES

The performance of a power source circuit using this device is highly dependent on a peripheral circuit. A peripheral component or the device mounted on PCB should not exceed a rated voltage, a rated current or a rated power. When designing a peripheral circuit, please be fully aware of the following points.

- Place the bypass capacitor (C_{IIN}) between the PVIN pin and the GND pin with shortest-distance wiring.
- Place the output capacitor (C_{OUT}) between the V_{OUT} pin and the GND pin with shortest-distance wiring. Connect GND of C_{OUT} to the GND pin with shortest-distance wiring.
- Make the GND plane wide.
- Ensure the PVIN and GND lines are firmly connected. A large switching current flows through the PVIN, GND, inductor, BOLX, BULX and V_{OUT} lines. If their impedance is too high, noise pickup or unstable operation may result.
- Connect the BOLX pin and the inductor and the BULX pin with shortest-distance wiring.

PCB LAYOUT CONSIDERATIONS

Current Paths on PCB

Figure 1 and Figure 2 show the current pathways of step-up circuit when NMOSFET is turned on. Figure 3 and Figure 4 show the current pathways of step-down circuit when PMOSFET is turned on.

The currents flow in the directions of blue or green arrows. The parasitic components, such as impedance, inductance or capacitance, formed in the pathways indicated by the red arrows affect the stability of the system and become the cause of noise. Reduce the parasitic components as much as possible. The current pathways should be made by short and thick wirings.

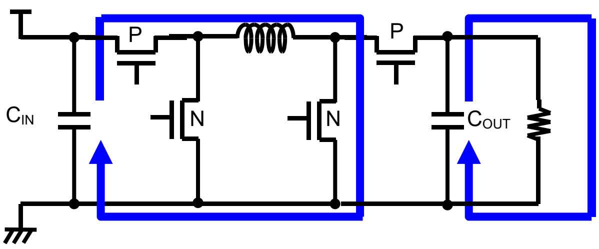


Figure 1. NMOSFET-ON (Step-up)

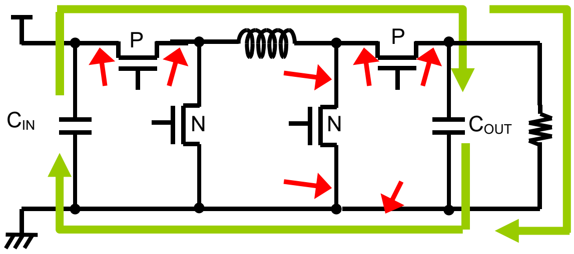


Figure 2. PMOSFET-ON (Step-up)

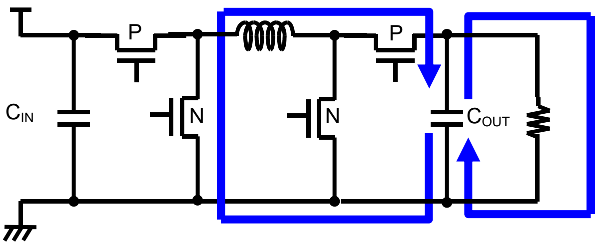


Figure 3. NMOSFET-ON (Step-down)

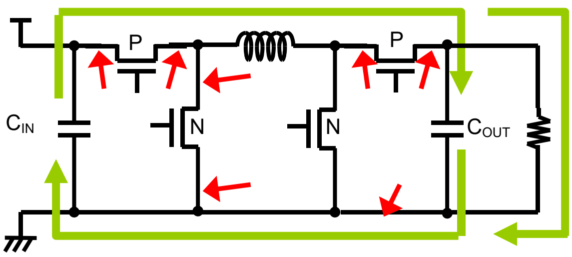
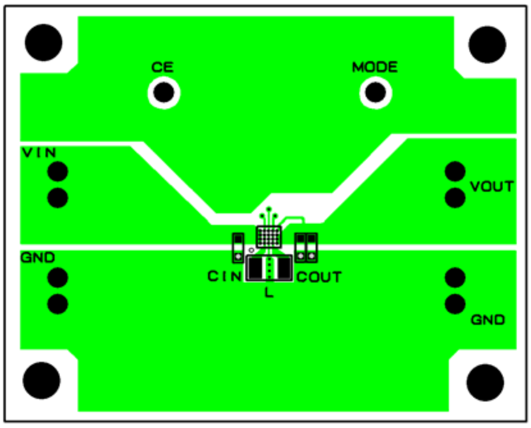


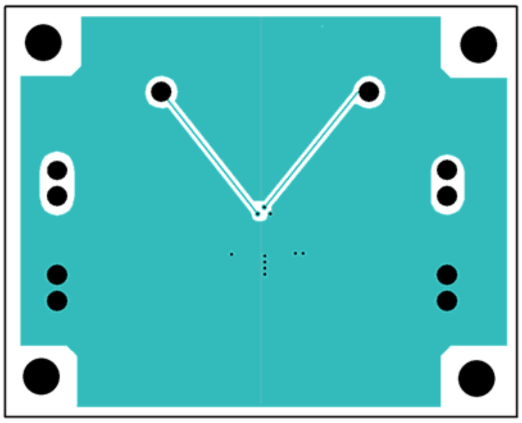
Figure 4. PMOSFET-ON (Step-down)

PCB LAYOUT

Top Layer

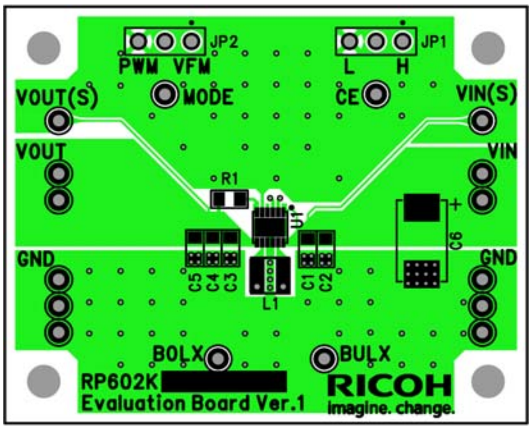


Bottom Layer

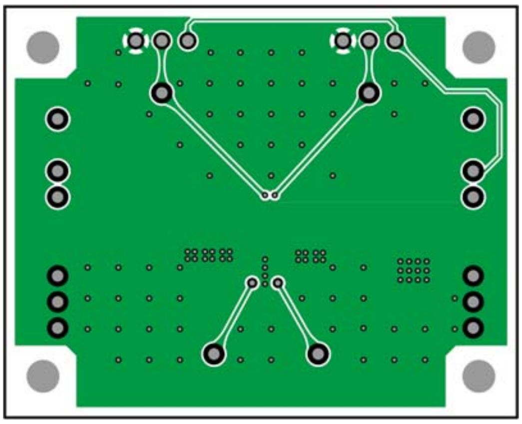


RP602x [PKG: WLCSP-20-P1] PCB Layout

Top Layer



Bottom Layer



RP602x [PKG: DFN(PLP)2730-12] PCB Layer

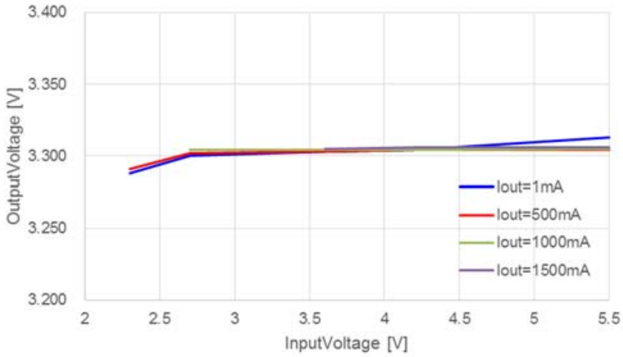
No. JA-353-190507

TYPICAL CHARACTERISTICS

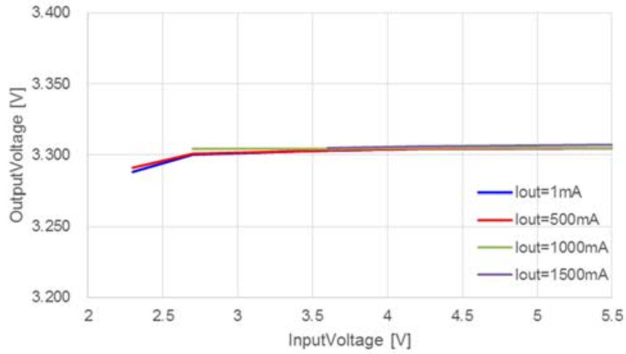
Note: Typical Characteristics are intended to be used as reference data; they are not guaranteed.

1) Input Voltage vs. Output Voltage

RP602Z330x, MODE = H

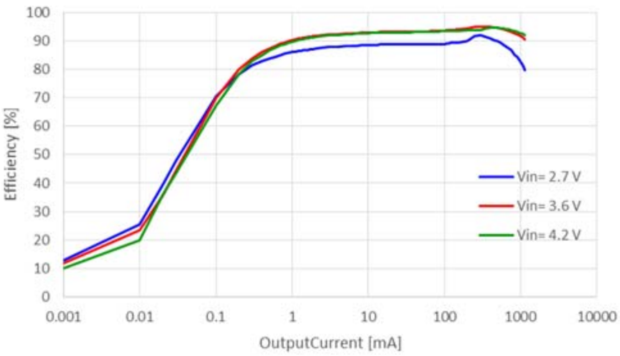


RP602Z330x, MODE = L

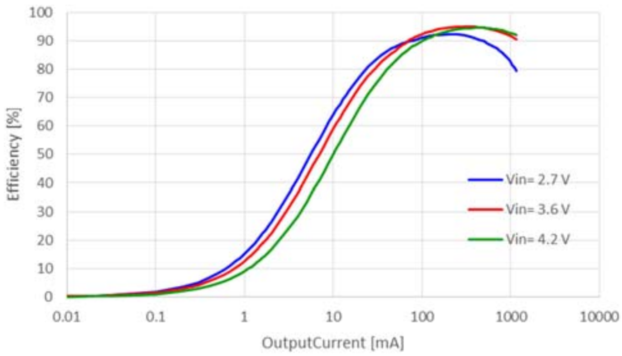


2) Output Current vs. Efficiency (for Different Input Voltages)

RP602Z330x, MODE = H

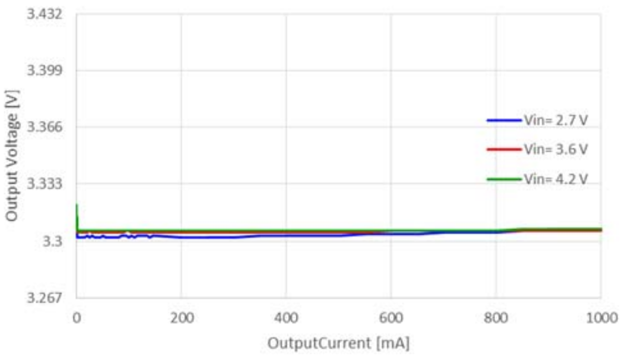


RP602Z330x, MODE = L

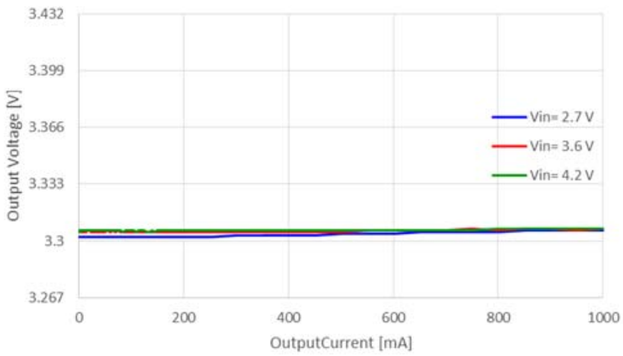


3) Output Current vs. Output Voltage

RP602Z330x, MODE = H

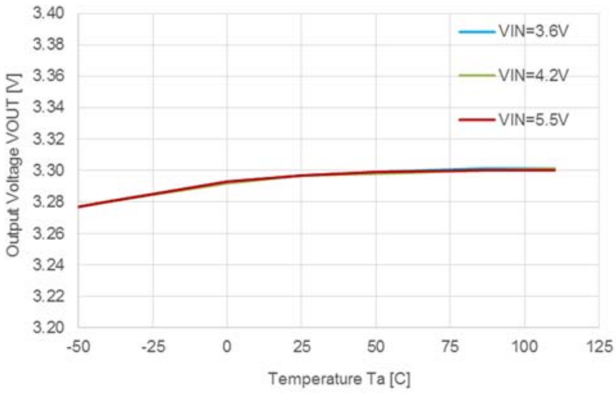


RP602Z330x, MODE = L

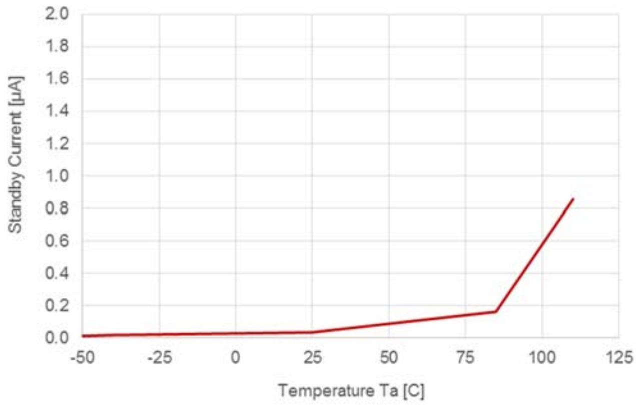


RICOH

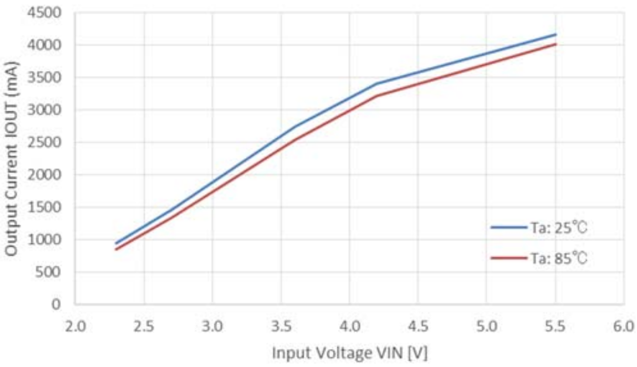
4) Temperature vs. Output Voltage
RP602Z330x



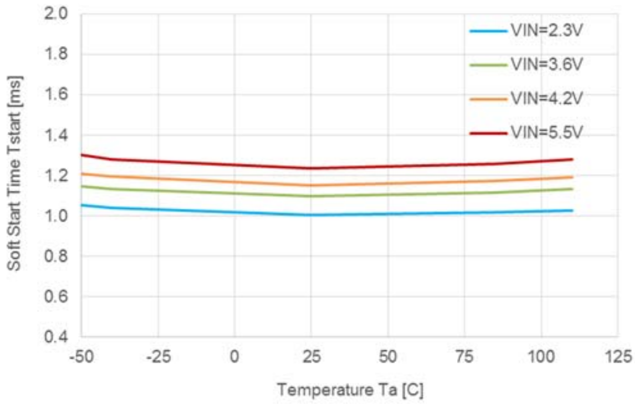
5) Temperature vs. Standby Current
RP602Z330x, V_{IN} = 5.5 V



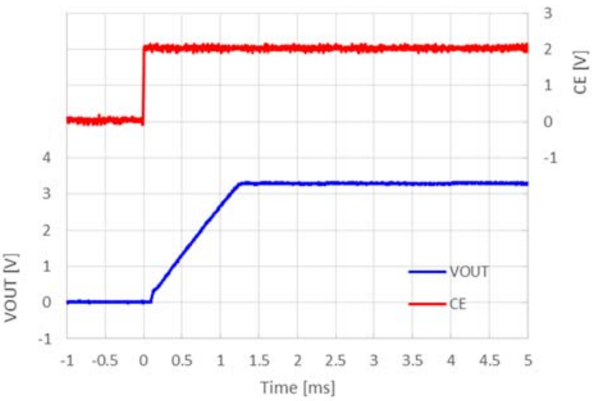
6) Input Voltage vs. Output Current
RP602Z330x, MODE = L



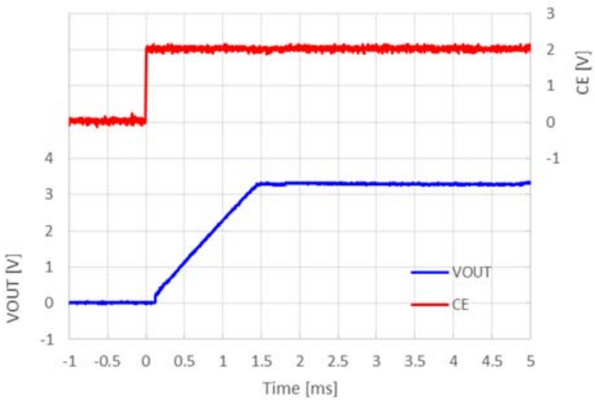
7) Temperature vs. Soft-start Time
RP602Z330x



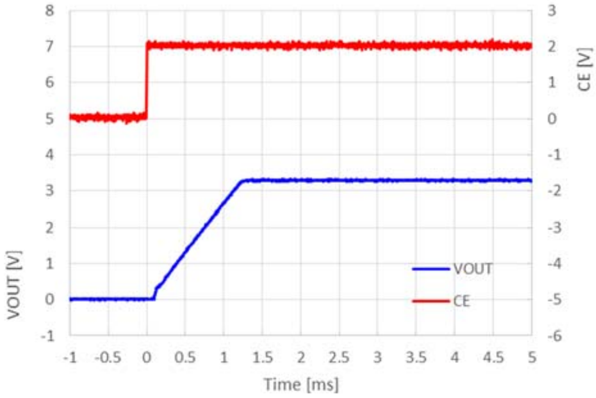
8) CE Start-up Waveform
RP602Z330x, V_{IN} = 3.6 V, MODE = H
I_{OUT} = 0 mA



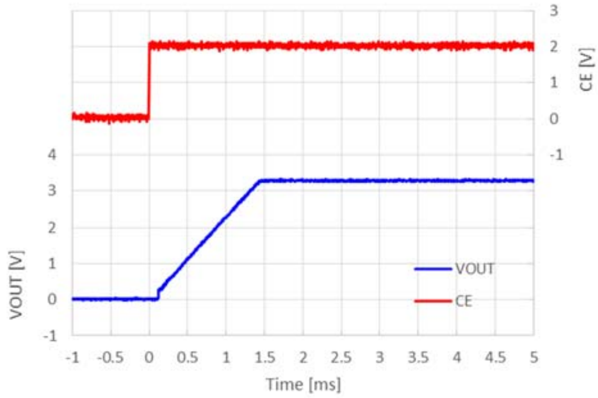
RP602Z330x, V_{IN} = 5.5 V, MODE = H
I_{OUT} = 0 mA



RP602Z330x, V_{IN} = 3.6 V, MODE = L
I_{OUT} = 0 mA

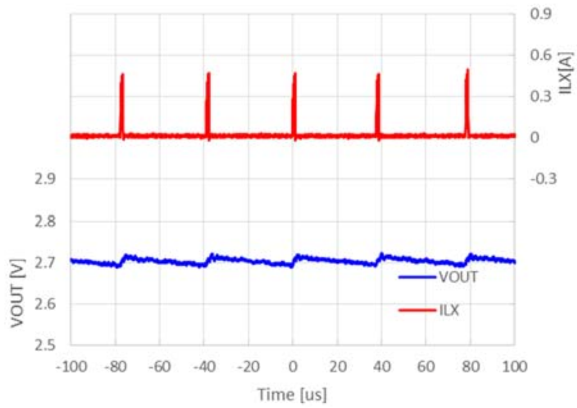


RP602Z330x, V_{IN} = 5.5 V, MODE = L
I_{OUT} = 0 mA

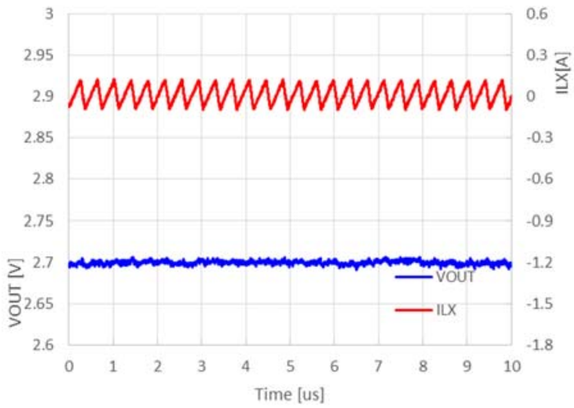


9) V_{OUT} Waveform

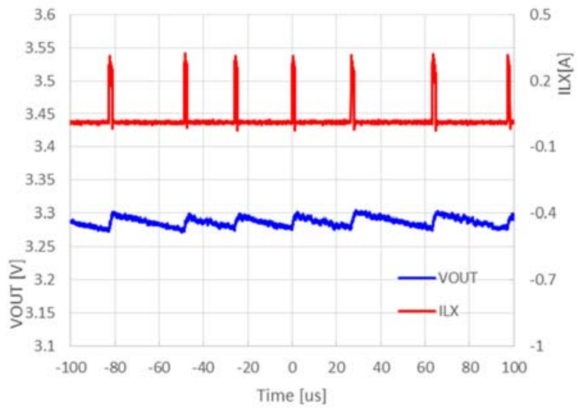
RP602Z270x, V_{IN} = 3.6 V, MODE = H
I_{OUT} = 10 mA



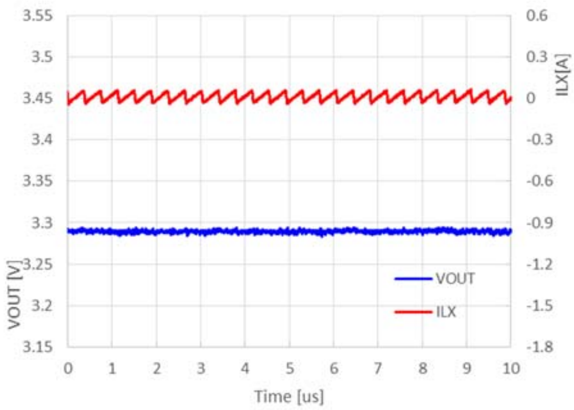
RP602Z270x, V_{IN} = 3.6 V, MODE = L
I_{OUT} = 0 mA



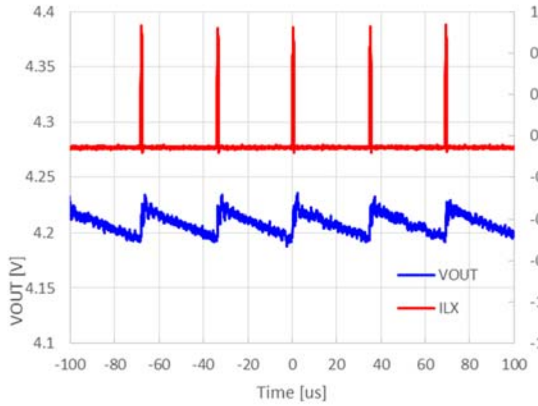
RP602Z330x, V_{IN} = 3.6 V, MODE = H
I_{OUT} = 10 mA



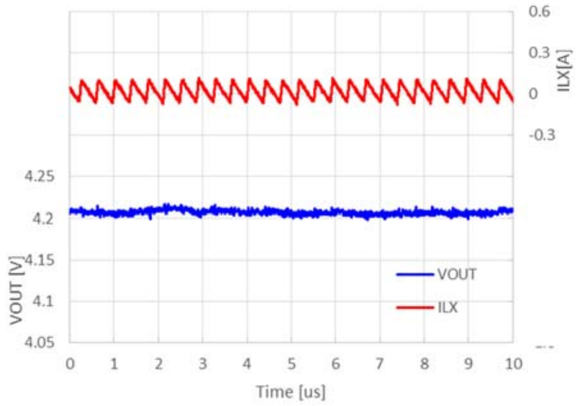
RP602Z330x, V_{IN} = 3.6 V, MODE = L
I_{OUT} = 0 mA



RP602Z420x, V_{IN} = 3.6 V, MODE = H
I_{OUT} = 10 mA

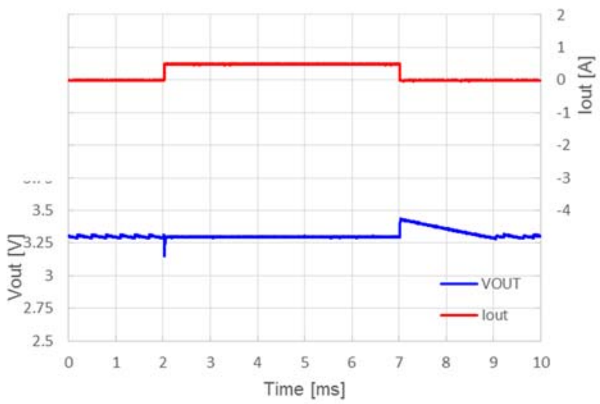


RP602Z420x, V_{IN} = 3.6 V, MODE = L
I_{OUT} = 0 mA

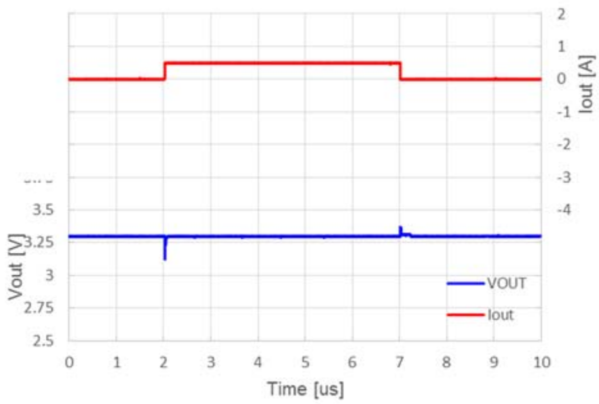


10) Load Transient Response Waveform

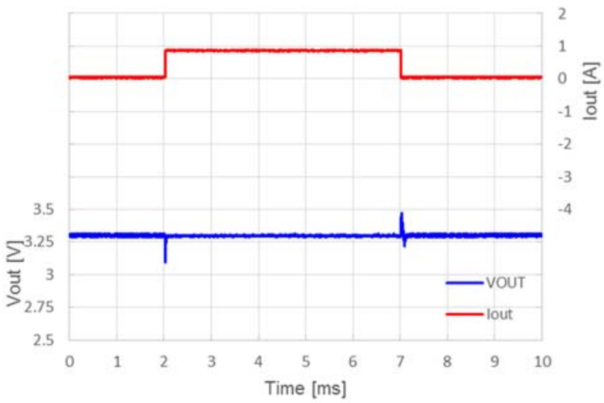
RP602Z330x, V_{IN} = 3.6 V, MODE = H
I_{OUT} = 1 mA ←→ 500 mA



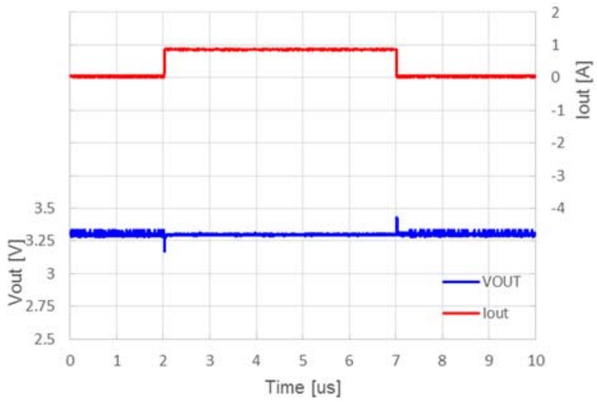
RP602Z330x, V_{IN} = 3.6 V, MODE = L
I_{OUT} = 1 mA ←→ 500 mA



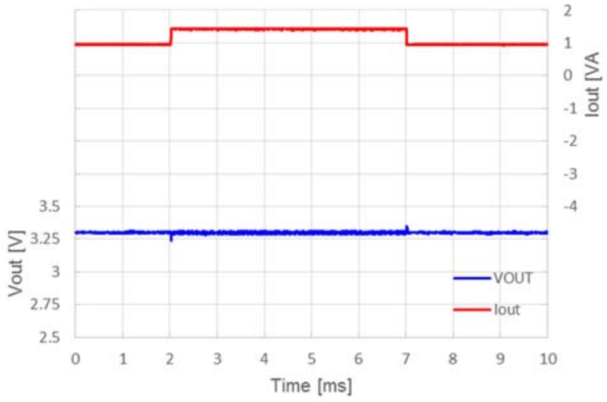
RP602Z330x, V_{IN} = 3.6 V, MODE = H
I_{OUT} = 50 mA ←→ 900 mA



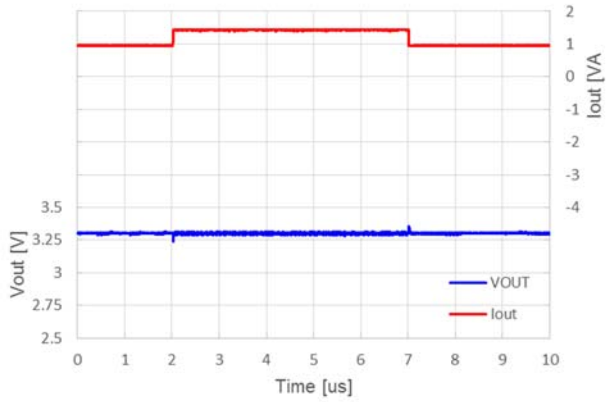
RP602Z330x, V_{IN} = 3.6 V, MODE = L
I_{OUT} = 50 mA ←→ 900 mA



RP602Z330x, V_{IN} = 3.6 V, MODE = H
I_{OUT} = 1000 mA ←→ 1500 mA

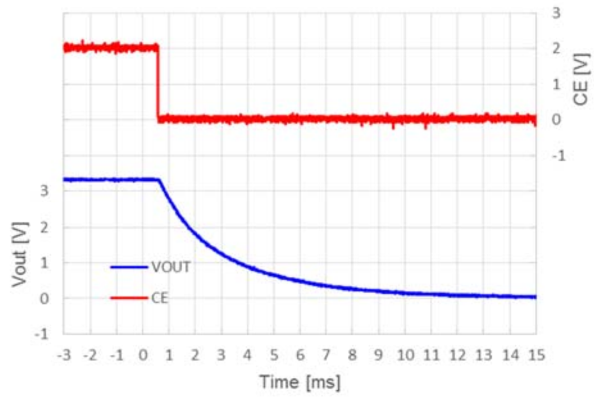


RP602Z330x, V_{IN} = 3.6 V, MODE = L
I_{OUT} = 1000 mA ←→ 1500 mA

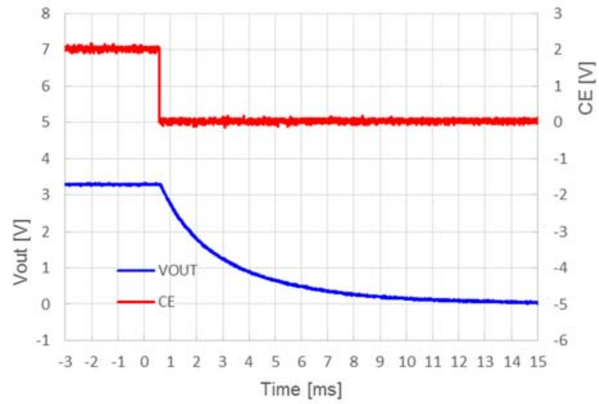


11) CE Turn off Waveform

RP602Z330x, V_{IN} = 3.6 V, MODE = H
I_{OUT} = 0 mA

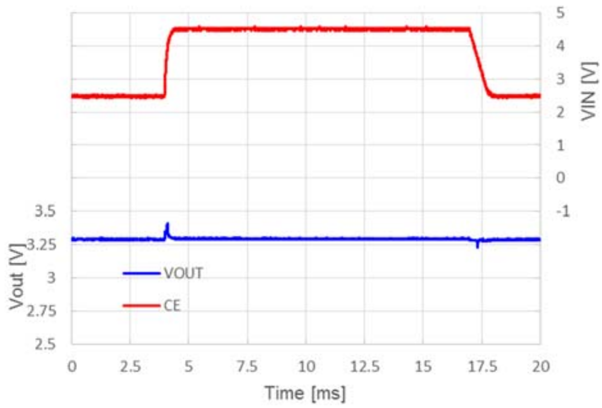


RP602Z330x, V_{IN} = 3.6 V, MODE = L
I_{OUT} = 0 mA

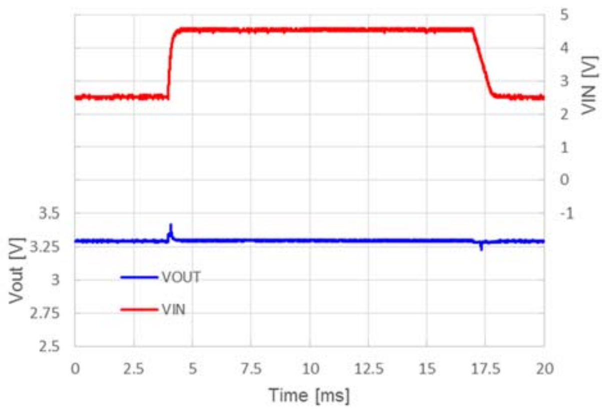


12) Input Transient Response Waveform

RP602Z330x, MODE = H
I_{OUT} = 500 mA, V_{IN} = 2.5 V ←→ 4.5 V



RP602Z330x, MODE = L
I_{OUT} = 500 mA, V_{IN} = 2.5 V ←→ 4.5 V



RICOH

Ver. B

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-9.

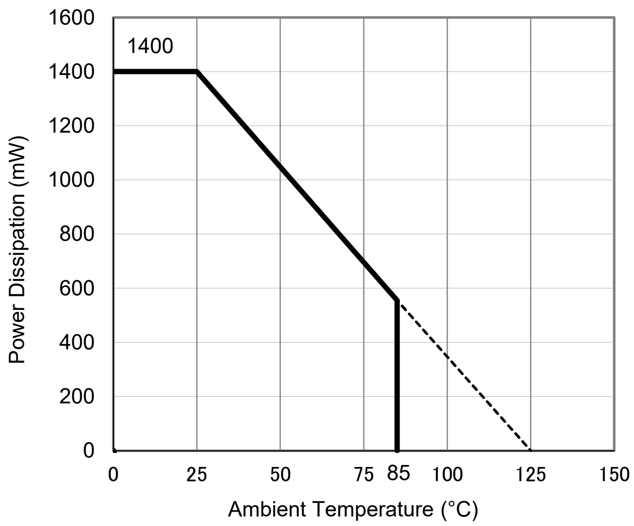
Measurement Conditions

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	101.5 mm x 114.5 mm x 1.6 mm
Copper Ratio	Outer Layers (First and Fourth Layers): 60% Inner Layers (Second and Third Layers): 100%

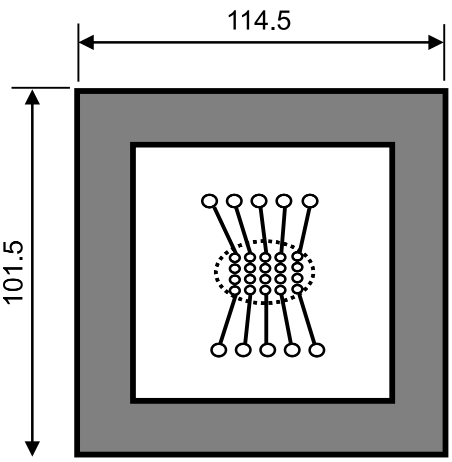
Measurement Result (Ta = 25°C, Tjmax = 125°C)

Item	Measurement Result
Power Dissipation	1400 mW
Thermal Resistance (θja)	θ ja = (125 − 25°C) / 1.4W = 71 °C/W

θja: Junction-to-Ambient Thermal Resistance

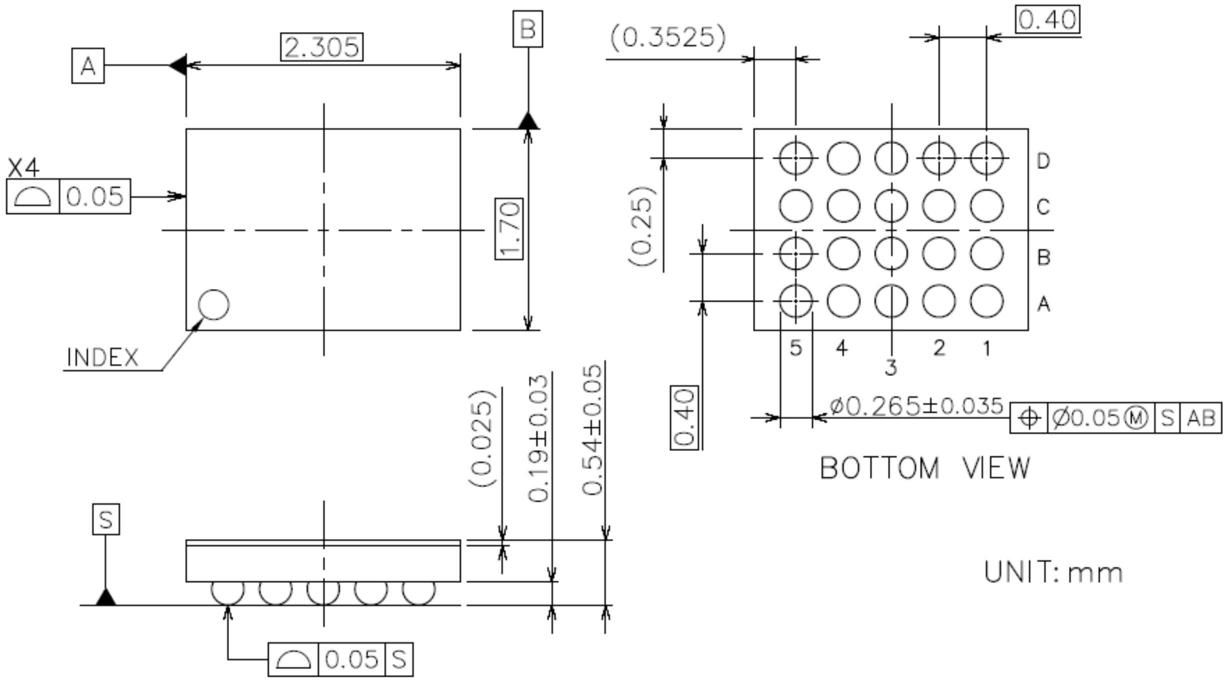


Power Dissipation vs. Ambient Temperature



Measurement Board Pattern

Ver. A



WLCSP-20-P1 Package Dimensions (Unit: mm)

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

Measurement Conditions

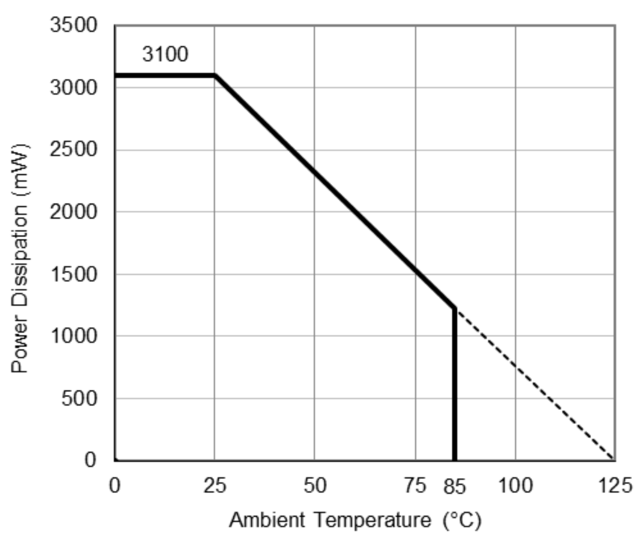
Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	ϕ 0.3 mm × 23 pcs

Measurement Result (Ta = 25°C, Tjmax = 125°C)

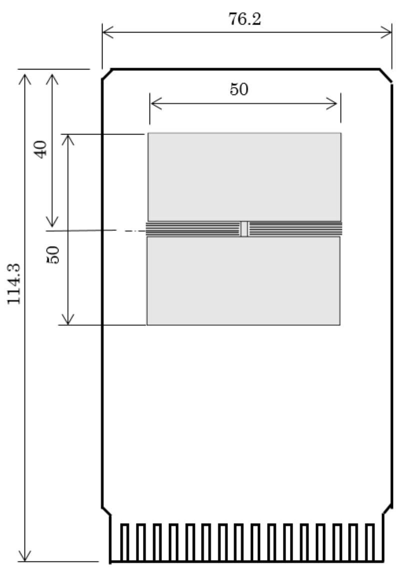
Item	Measurement Result
Power Dissipation	3100 mW
Thermal Resistance (θja)	θja = 32°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 8°C/W

θja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter



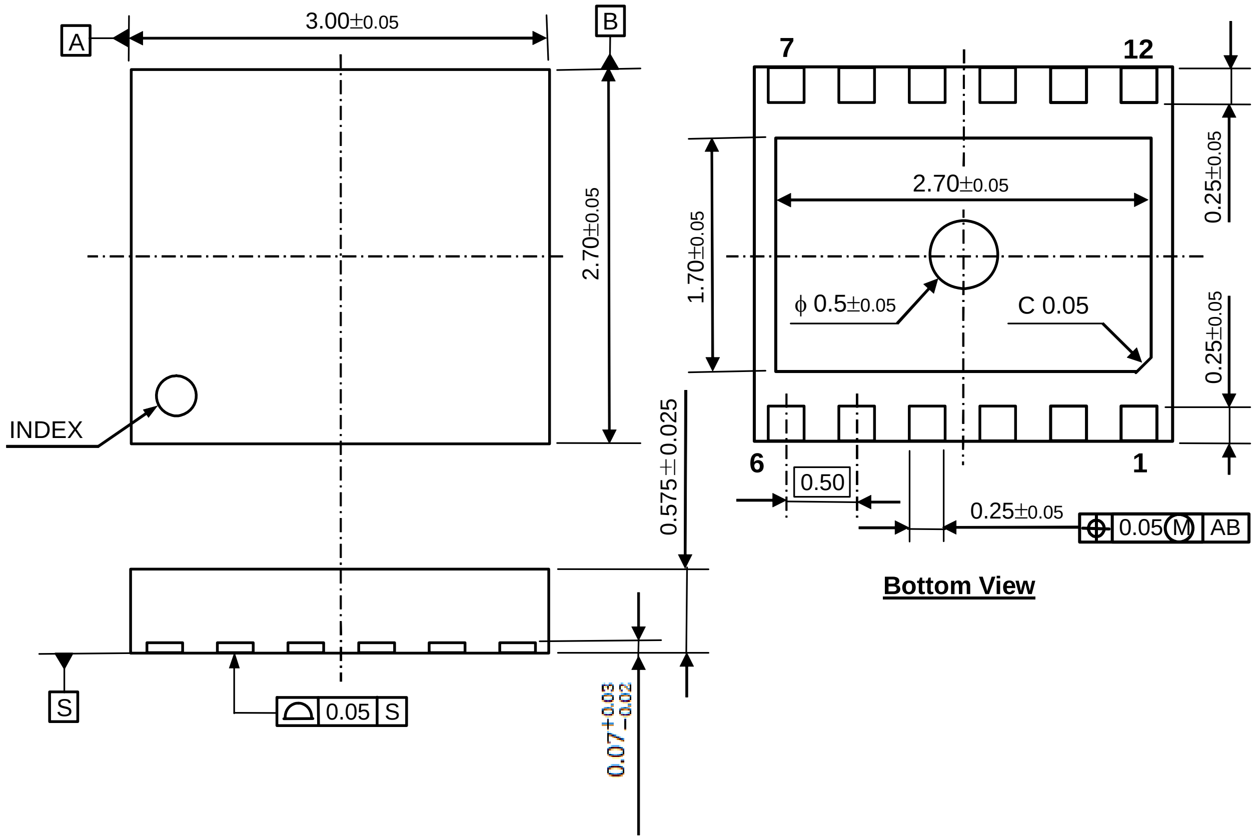
Power Dissipation vs. Ambient Temperature



Measurement Board Pattern

RICOH

Ver. A



DFN(PLP)2730-12 Package Dimensions (Unit: mm)

RoHS Compliant
Halogen Free

Ricoh is committed to reducing the environmental loading materials in electrical devices with a view to contributing to the protection of human health and the environment.
Ricoh has been providing RoHS compliant products since April 1, 2006 and Halogen-free products since April 1, 2012.

RICOH ELECTRONIC DEVICES CO., LTD.

https://www.e-devices.ricoh.co.jp/en/

Sales & Support Offices

Ricoh Electronic Devices Co., Ltd.
Shin-Yokohama Office (International Sales)
2-3, Shin-Yokohama 3-chome, Kohoku-ku, Yokohama-shi, Kanagawa, 222-8530, Japan
Phone: +81-50-3814-7687 Fax: +81-45-474-0074

Ricoh Americas Holdings, Inc.
675 Campbell Technology Parkway, Suite 200 Campbell, CA 95008, U.S.A.
Phone: +1-408-610-3105

Ricoh Europe (Netherlands) B.V.
Semiconductor Support Centre
Prof. W.H. Keesomlaan 1, 1183 DJ Amstelveen, The Netherlands
Phone: +31-20-5474-309

Ricoh International B.V. - German Branch
Semiconductor Sales and Support Centre
Oberrather Strasse 6, 40472 Düsseldorf, Germany
Phone: +49-211-6546-0

Ricoh Electronic Devices Korea Co., Ltd.
3F, Haesung Bldg, 504, Teheran-ro, Gangnam-gu, Seoul, 135-725, Korea
Phone: +82-2-2135-5700 Fax: +82-2-2051-5713

Ricoh Electronic Devices Shanghai Co., Ltd.
Room 403, No.2 Building, No.690 Bibo Road, Pu Dong New District, Shanghai 201203, People's Republic of China
Phone: +86-21-5027-3200 Fax: +86-21-5027-3299

Ricoh Electronic Devices Shanghai Co., Ltd.
Shenzhen Branch
1205, Block D(Jinlong Building), Kingkey 100, Hongbao Road, Luohu District, Shenzhen, China
Phone: +86-755-8348-7600 Ext 225

Ricoh Electronic Devices Co., Ltd.
Taipei office
Room 109, 10F-1, No.51, Hengyang Rd., Taipei City, Taiwan
Phone: +886-2-2313-1621/1622 Fax: +886-2-2313-1623